



LC72348G/W, 72349G/W

Low-Voltage ETR Controller with On-Chip LCD Driver

Overview

The LC72348G/W and LC72349G/W are low-voltage electronic tuning microcontrollers that include a PLL that operates up to 230 MHz and a 1/4 duty 1/2 bias LCD driver on chip. These ICs can contribute to further end product cost reduction than the LC72341 series while providing improved standby current characteristics. Also these ICs can use the application program for the LC72341 series except the IF counter function. These ICs are optimal for use in low-voltage portable audio equipment that includes a radio receiver.

Function

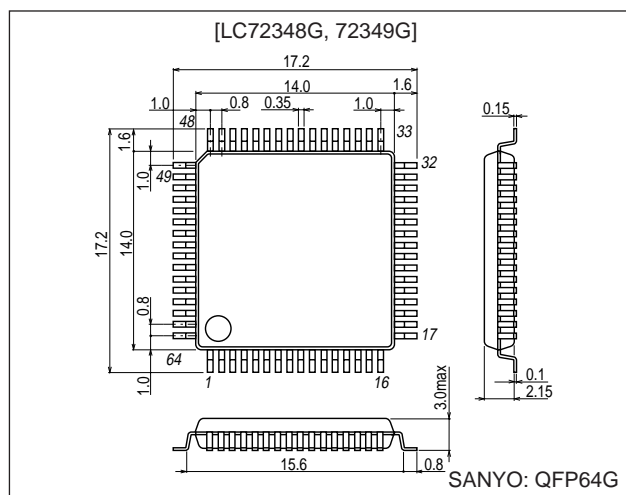
- Program memory (ROM):
 - 3072 × 16 bits (6K bytes) LC72348G/W
 - 4096 × 16 bits (8K bytes) LC72349 G/W
- Data memory (RAM):
 - 192 × 4 bits LC72348 G/W
 - 256 × 4 bits LC72349 G/W
- Cycle time: 40 μs (all 1-word instructions) at 75kHz crystal oscillation
- Stack: 8 levels
- LCD driver: 48 to 80 segments (1/4 duty, 1/2 bias drive)
- Interrupts: One external interrupt
 - Timer interrupts (1, 5, 10, and 50 ms)
- A/D converter: Three input channels
 - (5-bit successive approximation conversion)
- Input ports: 7 ports (of which three can be switched for use as A/D converter inputs)
- Output ports: 6 ports (of which 1 can be switched for use as the beep tone output and 2 are open-drain ports)
- I/O ports: 16 ports (of which 8 can be switched for use as LCD ports and as mask options)

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Package Dimensions

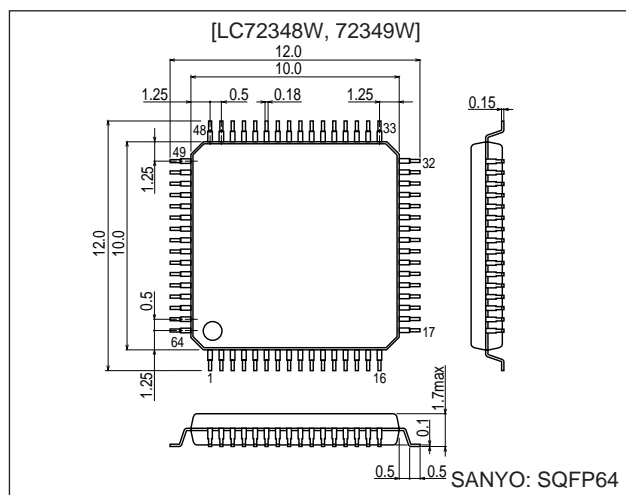
unit: mm

3231-QIP64G



unit: mm

3190-SQFP64



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- PLL: Supports dead zone control (two types)
- Reference frequencies: 1, 3, 3.125, 5, 6.25, 12.5, and 25 kHz
- Input frequencies: FM band: 10 to 230 MHz
AM band: 0.5 to 10 MHz
- Input sensitivity:
FM band: 35 mVrms (50 mVrms at 130 MHz or higher frequency)
AM band: 35 mVrms
- External reset input: During CPU and PLL operations, instruction execution is started from location 0.
- Built-in power-on reset circuit:
The CPU starts execution from location 0 when power is first applied.
- Halt mode: The controller-operating clock is stopped.
- Backup mode: The crystal oscillator is stopped.
- Static power-on function: Backup state is cleared with the PF port
- Beep tone: 1.5 and 3.1 kHz
- Built-in tuner voltage generating circuit:
Cost reduced in tuner-use power supply circuit
- Built-in low-pass filter amplifier
- Optional function switches:
 - PH0 to PH3 (general-purpose input, open-drain output/general-purpose input and output/S13 to S16)
 - PG0 to PG3 (general-purpose input, open-drain output/general-purpose input and output/S17 to S20)
 - VSENSE circuit (provided/not provided)
 - FM DC/DC clock (1/256, 75 kHz)
- Memory retention voltage: 0.9 V at least
- Package: SQFP-64 (0.5-mm pitch), QIC-64 (0.8-mm pitch)

Specifications

Absolute Maximum Ratings at Ta = 25°C, V_{SS} = 0 V

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{DD} max		−0.3 to +4.0	V
Input voltage	V _{IN}	All input pins	−0.3 to V _{DD} + 0.3	V
Output voltage	V _{OUT} (1)	AOUT, PE	−0.3 to +15	V
	V _{OUT} (2)	All output pins except V _{OUT} (1)	−0.3 to V _{DD} + 0.3	V
Output current	I _{OUT} (1)	PC, PD, PG, PH, EO	0 to 3	mA
	I _{OUT} (2)	PB	0 to 1	mA
	I _{OUT} (3)	AOUT, PE	0 to 2	mA
	I _{OUT} (4)	S1 to S20	300	μA
	I _{OUT} (5)	COM1 to COM4	3	mA
Allowable power dissipation	Pdmax	Ta = −20 to +70°C	300	mW
Operating temperature	T _{opr}		−20 to +70	°C
Storage temperature	T _{stg}		−45 to +125	°C

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Allowable Operating Ranges at Ta = -20 to +70°C, VDD = 1.8 to 3.6 V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Supply voltage	VDD(1)	PLL operating voltage	1.8	3.0	3.6	V
	VDD(2)	Memory retention voltage	1.0			
	VDD(3)	CPU operating voltage	1.4	3.0	3.6	
	VDD(4)	A/D converter operating voltage	1.6	3.0	3.6	
Input high-level voltage	VIH(1)	Input ports other than VIH(2), VIH(3), AMIN, FMIN, and XIN	0.7 VDD		VDD	V
	VIH(2)	RES	0.8 VDD		VDD	V
	VIH(3)	Port PF	0.6 VDD		VDD	V
Input low-level voltage	VIL(1)	Input ports other than VIL(2), VIL(3), AMIN, FMIN, and XIN	0		0.3 VDD	V
	VIL(2)	RES	0		0.2 VDD	V
	VIL(3)	Port PF	0		0.2 VDD	V
Input amplitude	VIN(1)	XIN	0.5		0.6	Vrms
	VIN(2)	FMIN, AMIN	0.035		0.35	Vrms
	VIN(3)	FMIN	0.05		0.35	Vrms
Input voltage range	VIN(5)	ADIO, ADI1, ADI3	0		VDD	V
Input frequency	FIN(1)	XIN: CI ≤ 35 kΩ	70	75	80	kHz
	FIN(2)	FMIN: VIN(2), VDD(1)	10		130	MHz
	FIN(3)	FMIN: VIN(3), VDD(1)	130		250	MHz
	FIN(4)	AMIN(L): VIN(2), VDD(1)	0.5		10	MHz

Electrical Characteristics within the allowable operating ranges

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input high-level current	IIH(1)	XIN: VI = VDD = 3.0 V			3	μA
	IIH(2)	FMIN, AMIN: VI = VDD = 3.0 V	3	8	20	μA
	IIH(3)	PA/PF (without pull-down resistors), the PC, PD, PG, and PH ports, and RES: VI = VDD = 3.0 V			3	μA
Input low-level current	IIL(1)	XIN: VI = VDD = VSS			-3	μA
	IIL(2)	FMIN, AMIN: VI = VDD = VSS	-3	-8	-20	μA
	IIL(3)	PA/PF (without pull-down resistors), the PC, PD, PG, and PH ports, and RES: VI = VDD = VSS			-3	μA
Input floating voltage	VIF	PA/PF (with pull-down resistors)			0.05 VDD	V
Pull-down resistor values	RPD(1)	PA/PF (with pull-down resistors), VDD = 3.0 V	75	100	200	kΩ
	RPD(2)	TEST1, TEST2		10		kΩ
Hysteresis	VH	RES	0.1 VDD	0.2 VDD		V
Voltage doubler reference voltage	DBR4	Referenced to VDD, C(3) = 0.47 μF, Ta = 25°C *1	1.3	1.5	1.7	V
Voltage doubler step-up voltage	DBR1, 2, 3	C(1) = 0.47 μF C(2) = 0.47 μF, without loading, Ta = 25°C *1	2.7	3.0	3.3	V
Output high-level voltage	VOH(1)	PB: IO = -1 mA	VDD - 0.7 VDD		VDD - 0.3 VDD	V
	VOH(2)	PC, PD, PG, PH: IO = -1 mA	VDD - 0.3 VDD			V
	VOH(3)	EO: IO = -500 μA	VDD - 0.3 VDD			V
	VOH(4)	XOUT: IO = -1 μA	VDD - 0.3 VDD			V
	VOH(5)	S1 to S20: IO = -20 μA *1	2.0			V
	VOH(6)	COM1, COM2, COM3, COM4: IO = -100 μA *1	2.0			V

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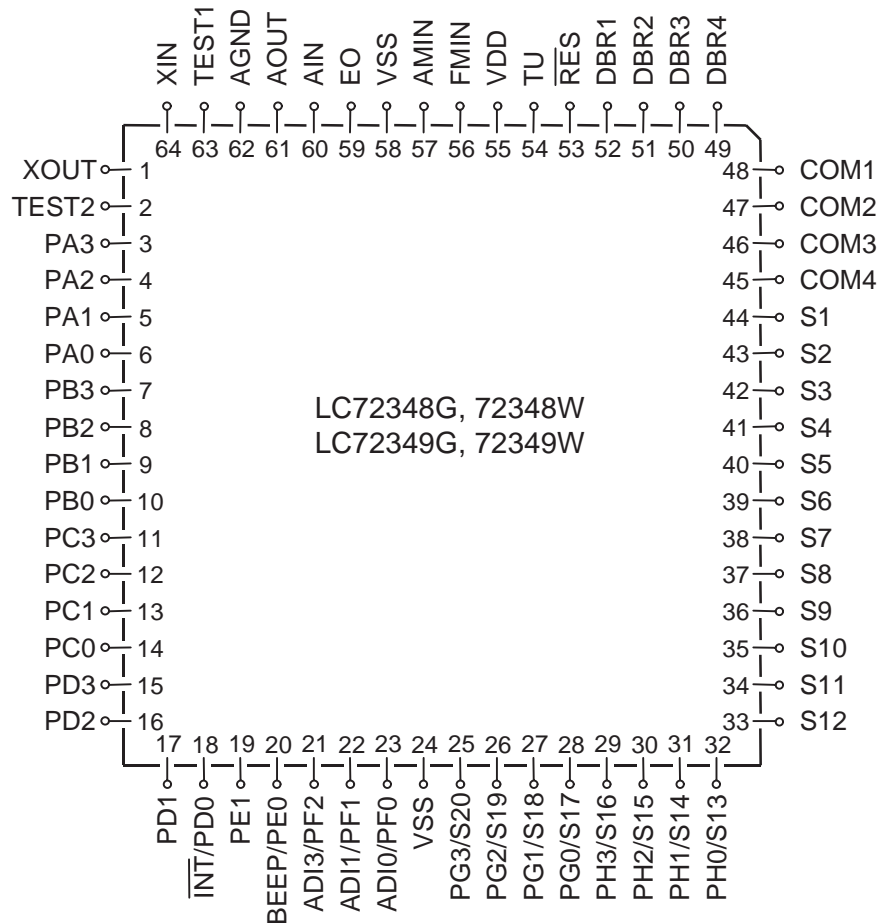
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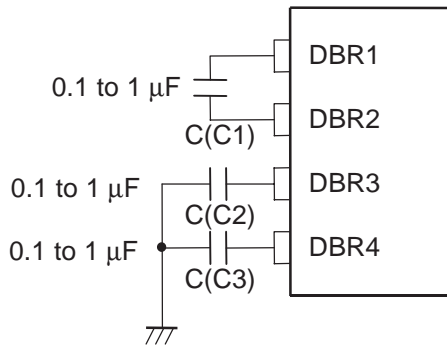
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output low-level voltage	V _{OL} (1)	PB: I _O = -50 μA	0.3 V _{DD}		0.7 V _{DD}	V
	V _{OL} (2)	PC, PD, PE, PG, PH: I _O = -1 mA			0.3 V _{DD}	V
	V _{OL} (3)	EO: I _O = -500 μA			0.3 V _{DD}	V
	V _{OL} (4)	XOUT: I _O = -1 μA			0.3 V _{DD}	V
	V _{OL} (5)	S1 to S20: I _O = -20 μA *1			1.0	V
	V _{OL} (6)	COM1, COM2, COM3, COM4: I _O = -100 μA *1			1.0	V
	V _{OL} (7)	PE: I _O = 2 mA			1.0	V
	V _{OL} (8)	AOUT(AIN = 1.3 V), TU: I _O = 1 mA, V _{DD} = 3 V			0.5	V
Output off leakage current	I _{OFF} (1)	Ports PB, PC, PD, PG, PH, and EO	-3		+3	μA
	I _{OFF} (2)	AOUT and port PE	-100		+100	nA
A/D converter error		ADI0, ADI1, ADI3 V _{DD} (4)	-1/2		+1/2	LSB
Supply voltage drop detection voltage	V _{SENSE} (1)	Ta = 25°C *2	1.6	1.75	1.9	V
Supply voltage rise detection voltage	V _{SENSE} (2)	Ta = 25°C *2	(1)min +0.1		(1)max +0.2	V
Current drain	I _{DD} (1)	V _{DD} (1): F _{IN} (2) 130 MHz, Ta = 25°C		5	15	mA
	I _{DD} (2)	V _{DD} (2): In HALT mode, Ta = 25°C *3		0.1		mA
	I _{DD} (3)	V _{DD} = 3.6 V, with the oscillator stopped, Ta = 25°C *4		1		μA
	I _{DD} (4)	V _{DD} = 1.8 V, with the oscillator stopped, Ta = 25°C *4		0.5		μA

Note: The halt mode current is due to the CPU executing 20 instruction steps every 125 ms.

Pin Assignment



Note: * C(1), C(2), and C(3) must be connected even if an LCD is not used.

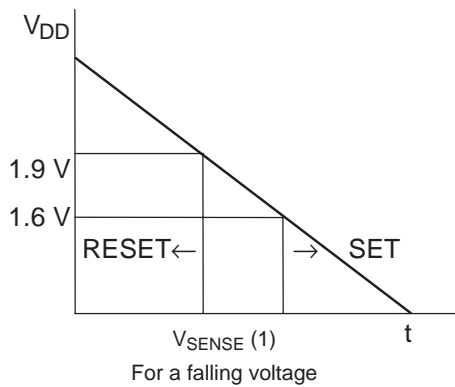


Notes: *1. The capacitors C(1), C(2), and C(3) must be connected to the DBR pins.

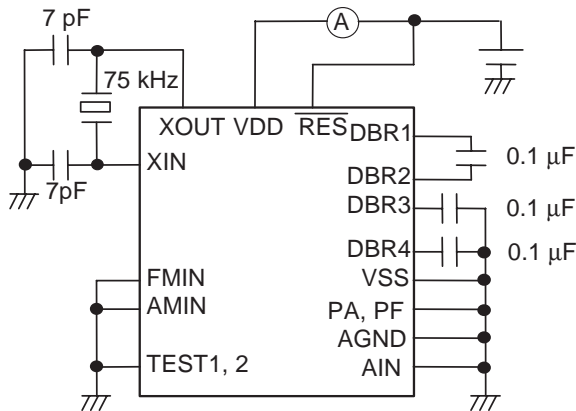
*2. V_{SENSE}

When the V_{DD} voltage drops, the V_{SENSE} flag is set when that voltage is 1.75 V (typical). Applications can check the V_{SENSE} flag using the TST instruction. Battery or other power source depletion can be easily measured by monitoring this flag.

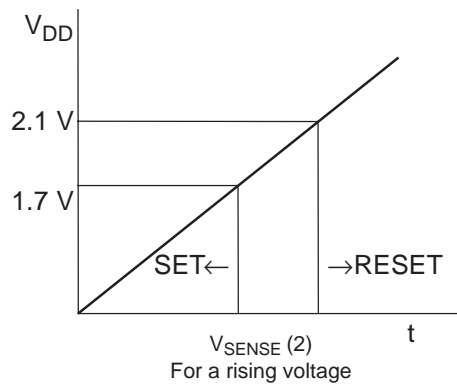
Note that the voltage for V_{SENSE} detection differs for the falling and rising directions. Thus, after the V_{SENSE} flag has been set due to a voltage drop, it will not be reset if the voltage rises by under 0.1 V.



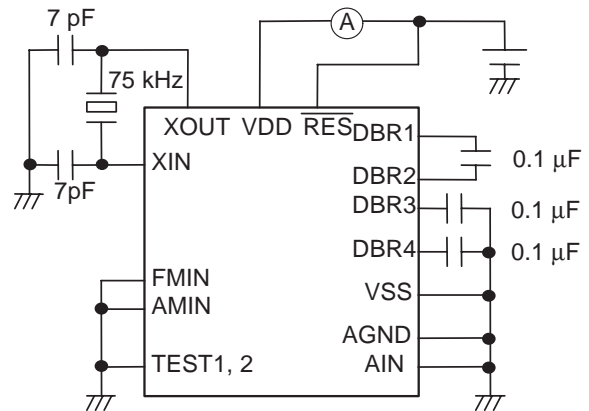
*3. Halt mode current measurement circuit



With all ports other than those specified above left open.
With output mode selected for PC and PD.
With segments S13 to S20 selected.

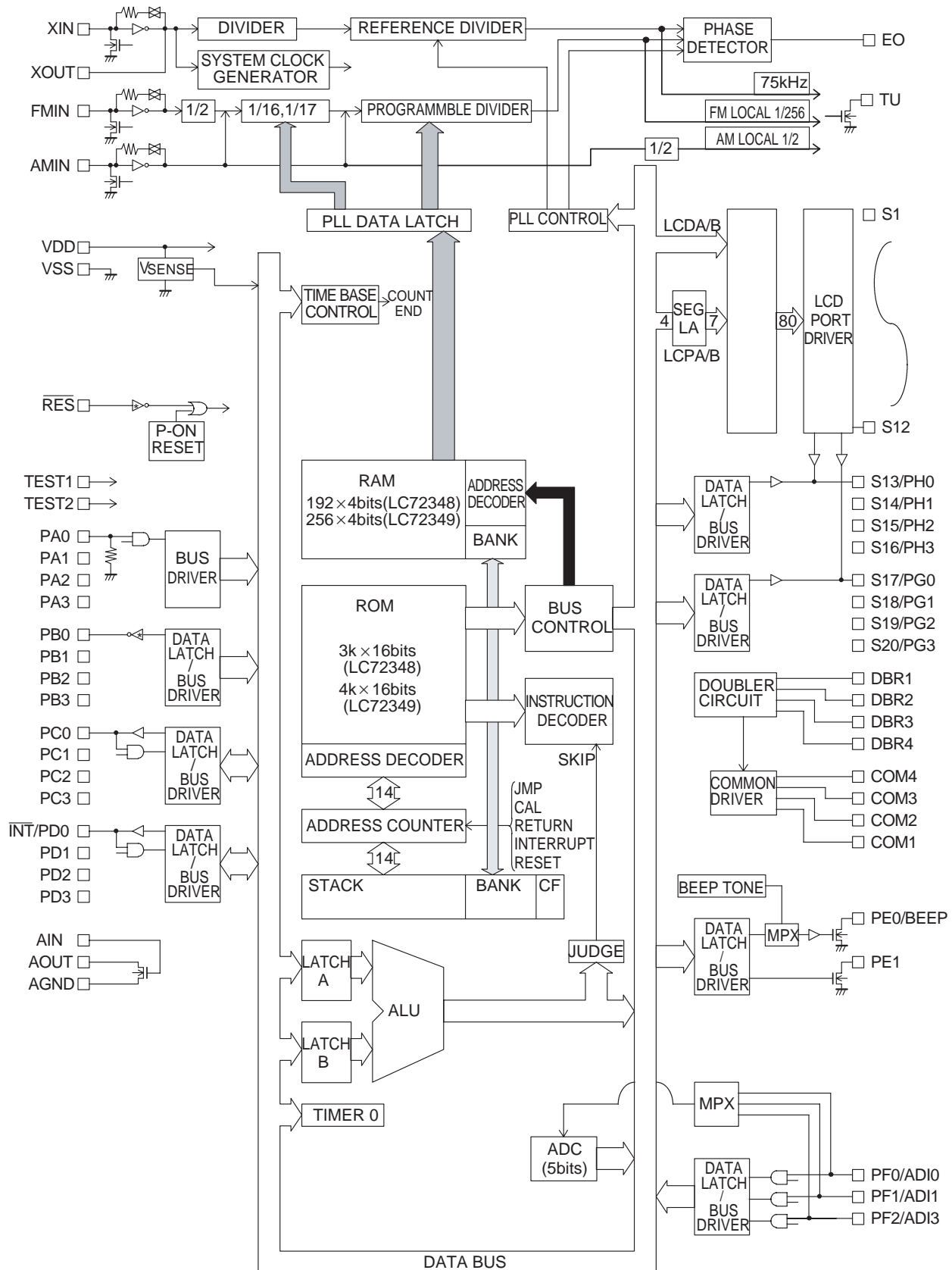


*4. Backup mode current measurement circuit

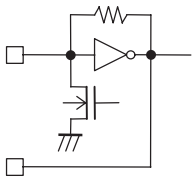
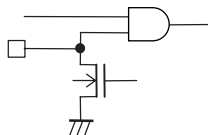
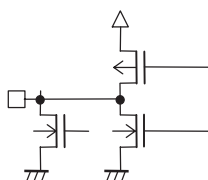
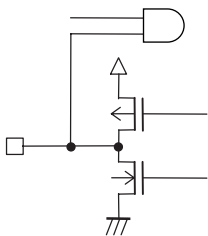
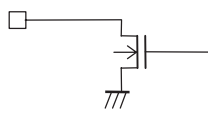


With all ports other than those specified above left open.
With output mode selected for PC and PD.
With segments S13 to S20 selected.

Block Diagram

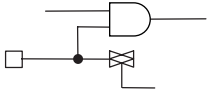
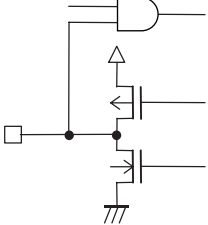
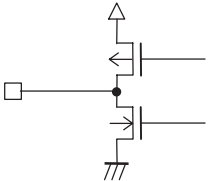
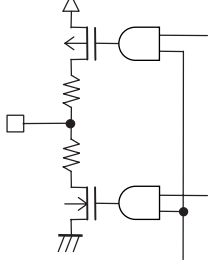


Pin Functions

Pin No.	Pin	I/O	Function	I/O circuit
64 1	XIN XOUT	I O	75 kHz oscillator connections	
63 2	TEST1 TEST2	I I	IC testing. These pins must be connected to ground during normal operation.	—
6 5 4 3	PA0 PA1 PA2 PA3	I	Special-purpose key return signal input ports designed with a low threshold voltage. When used in conjunction with port PB to form a key matrix, up to 3 simultaneous key presses can be detected. The four pull-down resistors are selected together in a single operation using the IOS instruction (PWN = 2, b1); they cannot be specified individually. Input is disabled in backup mode, and the pull-down resistors are disabled after a reset.	Input with built-in pull-down resistor 
10 9 8 7	PB0 PB1 PB2 PB3	O	General-purpose CMOS and n-channel open-drain output shared-function ports. The IOS instruction (Pwn = 2) is used for function switching. (b0: PB0, b2: PB1, b3: PB2, PB3) (0: general-purpose CMOS, 1: n-channel open-drain) Special-purpose key source signal output ports. Since unbalanced CMOS output transistor circuits are used, diodes to prevent short-circuits when multiple keys are pressed are not required. These ports go to the output high-impedance state in backup mode. These ports go to the output high-impedance state after a reset and remain in that state until an output instruction (OUT, SPB, or RPB) is executed. *: Verify the output impedance conditions carefully if these pins are used for functions other than key source outputs.	Unbalanced CMOS push-pull/n-channel open-drain 
14 13 12 11 18 17 16 15	PC0 PC1 PC2 PC3 INT/PD0 PD1 PD2 PD3 *2	I/O	General-purpose I/O ports. PD0 can be used as an external interrupt port. Input or output mode can be set individually using the IOS instruction by the bit (Pwn = 4, 5). A value of 0 specifies input, and 1 specifies output. These ports go to the input disabled high-impedance state in backup mode. They are set to function as general-purpose input ports after a reset.	CMOS push-pull 
20 19	BEEP/PE0 PE1		General-purpose output ports with shared beep tone output function (PE0 only). The BEEP instruction is used to switch PE0 between the general-purpose output port and beep tone output functions. To use PE0 as a general-purpose output port, execute a BEEP instruction with b2 set to 0. Set b2 to 1 to use PE0 as the beep tone output port. The b0 and b1 bits are used to select the beep tone frequency. There are two beep tone frequencies supported. *: When PE0 is set up as the beep tone output, executing an output instruction to PE0 only changes the state of the internal output latch, it does not affect the beep tone output in any way. Only the PE0 pin can be switched between the general-purpose output function and the beep tone output function; the PE1 pin only functions as a general-purpose output. These pins go to the high-impedance state in backup mode and remain in that state until an output instruction or a BEEP instruction is executed. Since these ports are open-drain ports, resistors must be inserted between these pins and VDD. These ports are set to general-purpose output port function after a reset.	N-channel open-drain 

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Pin No.	Pin	I/O	Function	I/O circuit
23 22 21	PF0/ADI0 PF1/ADI1 PF2/ADI3	I	<p>General-purpose input and A/D converter input shared function ports. The IOS instruction (Pwn = FH) is used to switch between the general-purpose input and A/D converter port functions. The general-purpose input and A/D converter port functions can be switched by the bit, with 0 specifying general-purpose input, and 1 specifying the A/D converter input function. To select the A/D converter function, set up the A/D converter pin with an IOS instruction with Pwn set to 1. The A/D converter is started with the UCC instruction (b3 = 1, b2 = 1). The ADCE flag is set when the conversion completes. The INR instruction is used to read in the data.</p> <p>*: If an input instruction is executed for one of these pins which is set up for analog input, the read in data will be at the low level since CMOS input is disabled. In backup mode these pins go to the input disabled high-impedance state. These ports are set to their general-purpose input port function after a reset. The A/D converter is a 5-bit successive approximation type converter, and features a conversion time of 1.28 ms. Note that the full-scale A/D converter voltage (1FH) is (63.96) V_{DD}.</p>	<p>CMOS input/analog input</p> 
25 26 27 28 29 30 31 32	PG3/S20 PG2/S19 PG1/S18 PG0/S17 PH3/S16 PH2/S15 PH1/S14 PH0/S13 *2	I/O	<p>LCD driver segment output, general-purpose I/O, and general-purpose n-channel open-drain output shared function ports.</p> <p>The IOS instruction is used for switching between the segment output and general-purpose I/O functions.</p> <ul style="list-style-type: none"> When used as segment output ports The general-purpose I/O port function is selected with the IOS instruction (Pwn = 8). b0 = S17 to 20/PG0 to 3 (0: Segment output, 1: PG0 to 3) The general-purpose I/O port function is selected with the IOS instruction (Pwn = 9). b0 = S13 to 16/PH0 to 3 (0: Segment output, 1: PH0 to 3) When used as general-purpose I/O ports The IOS instruction (Pwn = 6,7) is used to select input or output. Note that the mode can be set in individual by the bit. <div style="display: flex; justify-content: space-around; align-items: center;"> <div style="text-align: center;"> <p>b0 = PG0 b1 = PG1 b2 = PG2 b3 = PG3</p> <p>0: Input 1: Output</p> </div> <div style="text-align: center;"> <p>b0 = PH0 b1 = PH1 b2 = PH2 b3 = PH3</p> <p>0: Input 1: Output</p> </div> </div> <p>In backup mode, these pins go to the input disabled high-impedance state if set up as general-purpose outputs, and are fixed at the low level if set up as segment outputs. These ports are set up as segment outputs after a reset.</p> <p>Although the general-purpose I/O port/general-purpose n-channel open-drain output/LCD port setting is a mask option, the IOS instruction must be used as described above to set up the port function.</p>	<p>CMOS push-pull</p> 
33 to 44	S16 to S1	O	<p>LCD driver segment output pins.</p> <p>A 1/4-duty 1/2-bias drive technique is used.</p> <p>The frame frequency is 75 Hz.</p> <p>In backup mode, the outputs are fixed at the low level.</p> <p>After a reset, the outputs are fixed at the low level.</p>	<p>CMOS push-pull</p> 
45 46 47 48	COM4 COM3 COM2 COM1	O	<p>LCD driver common output pins.</p> <p>A 1/4-duty 1/2-bias drive technique is used.</p> <p>The frame frequency is 75 Hz.</p> <p>In backup mode, the outputs are fixed at the low level.</p> <p>After a reset, the outputs are fixed at the low level.</p>	
49 50 51 52	DBR4 DBR3 DBR2 DBR1	I	LCD power supply step-up voltage inputs.	

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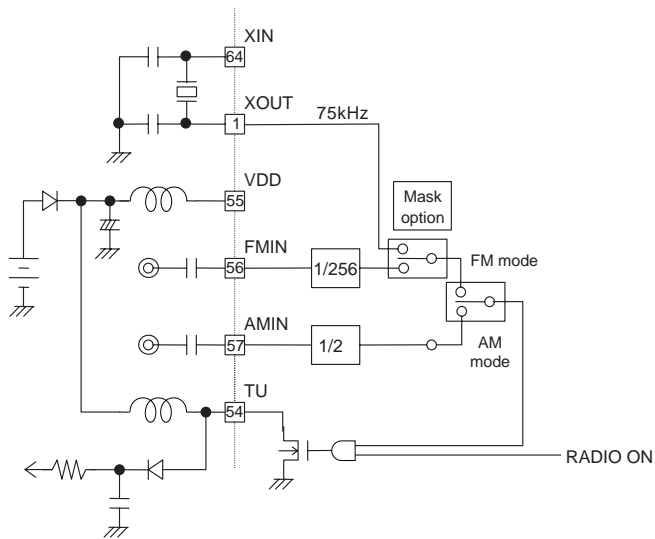
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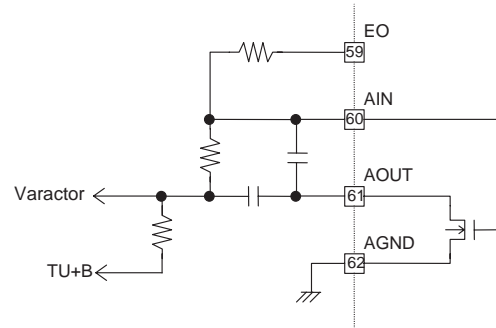
Pin No.	Pin	I/O	Function	I/O circuit						
53	$\overline{\text{RES}}$	I	System reset input. In CPU operating mode or halt mode, applications must apply a low level for at least one full machine cycle to reset the system and restart execution with the PC set to location 0. This pin is connected in parallel with the internal power on reset circuit.							
54	TU	O	Tuning voltage generation circuit outputs. These pins include an n-channel transistor, and a tuning voltage can be generated by connecting external coil, diode, and capacitor components. FM DC-DC clock switching is a mask option. <table border="1"><tr><td></td><td>DC-DC clock</td></tr><tr><td>AM</td><td>AM local 1/2</td></tr><tr><td>FM</td><td>FM local 1/256 or 75 kHz</td></tr></table>		DC-DC clock	AM	AM local 1/2	FM	FM local 1/256 or 75 kHz	N-channel open-drain
	DC-DC clock									
AM	AM local 1/2									
FM	FM local 1/256 or 75 kHz									
56	FMIN	I	FM VCO (local oscillator) input. This pin is selected with the PLL instruction CW1. The input must be capacitor coupled. Input is disabled in backup mode, in halt mode, after a reset, and in PLL stop mode.	CMOS amplifier input 						
57	AMIN	I	AM VCO (local oscillator) input. This pin and the bandwidth are selected with the PLL instruction CW1. <table border="1"><tr><td>CW1</td><td>b1, b0</td><td>Bandwidth</td></tr><tr><td>1</td><td>1</td><td>0.5 to 10 MHz (MW, LW)</td></tr></table> The input must be capacitor coupled. Input is disabled in backup mode, in halt mode, after a reset, and in PLL stop mode.	CW1	b1, b0	Bandwidth	1	1	0.5 to 10 MHz (MW, LW)	CMOS amplifier input
CW1	b1, b0	Bandwidth								
1	1	0.5 to 10 MHz (MW, LW)								
59	EO	O	Main charge pump output. When the local oscillator frequency divided by N is higher than the reference frequency a high level is output, when lower, a low level is output. The pin is set to the high-impedance state when the frequencies match. Output goes to the high-impedance state in backup mode, in halt mode, after a reset, and in PLL stop mode.	CMOS push-pull 						
60 61 62	AIN AOUT AGND	O	Transistor used for the low-pass filter amplifier. Connect AGND to ground.							
24 58 55	VSS VSS VDD	—	Power supply pin. This pin must be connected to ground. This pin must be connected to ground. This pin must be connected to VDD.	—						

Note 2: When a pin in an I/O switching port is used as an output, applications must first set up the data with an OUT, SPB, or RPB instruction and then set up output mode with an IOS instruction.

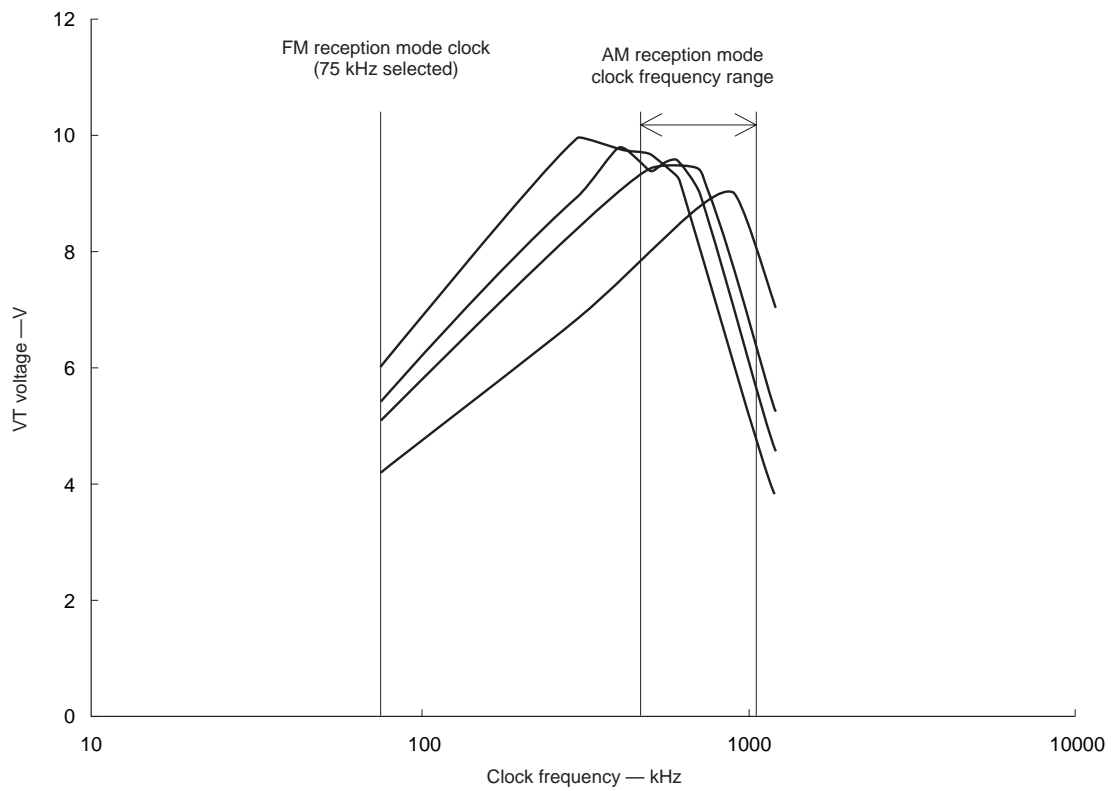
Sample Application for Tuning Voltage Generation Circuit



Sample Application for Low-Pass Filter Amplifier



LC72348 DC-DC converter load: 100 kΩ



LC72340 Series Instruction Set

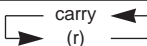
Terminology

ADDR	: Program memory address
b	: Borrow
C	: Carry
DH	: Data memory address High (Row address) [2 bits]
DL	: Data memory address Low (Column address) [4 bits]
I	: Immediate data [4 bits]
M	: Data memory address
N	: Bit position [4 bits]
Rn	: Resister number [4 bits]
Pn	: Port number [4 bits]
PW	: Port control word number [4 bits]
r	: General register (One of the addresses from 00H to 0FH of BANK0)
(), []	: Contents of register or memory
M (DH, DL)	: Data memory specified by DH, DL

Instruc- tions	Mnemonic	Operand		Function	Operations function	Instruction format															
		1st	2nd			f	e	d	c	b	a	9	8	7	6	5	4	3	2	1	0
Addition instructions	AD	r	M	Add M to r	$r \leftarrow (r) + (M)$	0	1	0	0	0	0		DH		DL				r		
	ADS	r	M	Add M to r, then skip if carry	$r \leftarrow (r) + (M)$, skip if carry	0	1	0	0	0	1		DH		DL				r		
	AC	r	M	Add M to r with carry	$r \leftarrow (r) + (M) + C$	0	1	0	0	1	0		DH		DL				r		
	ACS	r	M	Add M to r with carry, then skip if carry	$r \leftarrow (r) + (M) + C$ skip if carry	0	1	0	0	1	1		DH		DL				r		
	AI	M	I	Add I to M	$M \leftarrow (M) + I$	0	1	0	1	0	0		DH		DL				I		
	AIS	M	I	Add I to M, then skip if carry	$M \leftarrow (M) + I$, skip if carry	0	1	0	1	0	1		DH		DL				I		
	AIC	M	I	Add I to M with carry	$M \leftarrow (M) + I + C$	0	1	0	1	1	0		DH		DL				I		
	AICS	M	I	Add I to M with carry, then skip if carry	$M \leftarrow (M) + I + C$, skip if carry	0	1	0	1	1	1		DH		DL				I		
Subtraction instructions	SU	r	M	Subtract M from r	$r \leftarrow (r) - (M)$	0	1	1	0	0	0		DH		DL				r		
	SUS	r	M	Subtract M from r, then skip if borrow	$r \leftarrow (r) - (M)$, skip if borrow	0	1	1	0	0	1		DH		DL				r		
	SB	r	M	Subtract M from r with borrow	$r \leftarrow (r) - (M) - b$	0	1	1	0	1	0		DH		DL				r		
	SBS	r	M	Subtract M from r with borrow, then skip if borrow	$r \leftarrow (r) - (M) - b$, skip if borrow	0	1	1	0	1	1		DH		DL				r		
	SI	M	I	Subtract I from M	$M \leftarrow (M) - I$	0	1	1	1	0	0		DH		DL				I		
	SIS	M	I	Subtract I from M, then skip if borrow	$M \leftarrow (M) - I$, skip if borrow	0	1	1	1	0	1		DH		DL				I		
	SIB	M	I	Subtract I from M with borrow	$M \leftarrow (M) - I - b$	0	1	1	1	1	0		DH		DL				I		
	SIBS	M	I	Subtract I from M with borrow, then skip if borrow	$M \leftarrow (M) - I - b$, skip if borrow	0	1	1	1	1	1		DH		DL				I		

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Instructions	Mnemonic	Operand		Function	Operations function	Instruction format															
		1st	2nd			f	e	d	c	b	a	9	8	7	6	5	4	3	2	1	0
Comparison instructions	SEQ	r	M	Skip if r equal to M	$(r) - (M)$, skip if zero	0	0	0	1	0	0		DH		DL					r	
	SEQL	M	I	Skip if M equal to I	$(M) - I$, skip if zero	0	0	0	1	0	1		DH		DL					I	
	SNEI	M	I	Skip if M not equal to I	$(M) - I$, skip if not zero	0	0	0	0	0	1		DH		DL					I	
	SGE	r	M	Skip if r is greater than or equal to M	$(r) - (M)$, skip if not borrow	0	0	0	1	1	0		DH		DL					r	
	SGEI	M	I	Skip if M is greater than equal to I	$(M) - I$, skip if not borrow	0	0	0	1	1	1		DH		DL					I	
	SLEI	M	I	Skip if M is less than I	$(M) - I$, skip if borrow	0	0	0	0	1	1		DH		DL					I	
Logic instructions	AND	r	M	AND M with r	$r \leftarrow (r) \text{ AND } (M)$	0	0	1	0	0	0		DH		DL					r	
	ANDI	M	I	AND I with M	$M \leftarrow (M) \text{ AND } I$	0	0	1	0	0	1		DH		DL					I	
	OR	r	M	OR M with r	$r \leftarrow (r) \text{ OR } (M)$	0	0	1	0	1	0		DH		DL					r	
	ORI	M	I	OR I with M	$M \leftarrow (M) \text{ OR } I$	0	0	1	0	1	1		DH		DL					I	
	EXL	r	M	Exclusive OR M with r	$r \leftarrow (r) \text{ XOR } (M)$	0	0	1	1	0	0		DH		DL					r	
	EXLI	M	I	Exclusive OR M with M	$M \leftarrow (M) \text{ XOR } I$	0	0	1	1	0	1		DH		DL					I	
	SHR	r		Shift r right with carry		0	0	0	0	0	0		0	0	1	1	1	0			r
Transfer instructions	LD	r	M	Load M to r	$r \leftarrow (M)$	1	1	0	1	0	0		DH		DL					r	
	ST	M	r	Store r to M	$M \leftarrow (r)$	1	1	0	1	0	1		DH		DL					r	
	MVRD	r	M	Move M to destination M referring to r in the same row	$[DH, Rn] \leftarrow (M)$	1	1	0	1	1	0		DH		DL					r	
	MVRS	M	r	Move source M referring to r to M in the same row	$M \leftarrow [DH, Rn]$	1	1	0	1	1	1		DH		DL					r	
	MVSR	M1	M2	Move M to M in the same row	$[DH, DL1] \leftarrow [DH, DL2]$	1	1	1	0	0	0		DH		DL1					DL2	
	MVI	M	I	Move I to M	$M \leftarrow I$	1	1	1	0	0	1		DH		DL					I	
Bit test instructions	TMT	M	N	Test M bits, then skip if all bits specified are true	if M (N) = all 1s, then skip	1	1	1	1	0	0		DH		DL					N	
	TMF	M	N	Test M bits, then skip if all bits specified are false	if M (N) = all 0s, then skip	1	1	1	1	0	1		DH		DL					N	
Jump and subroutine call instructions	JMP	ADDR		Jump to the address	$PC \leftarrow ADDR$	1	0	0	ADDR (13 bits)												
	CAL	ADDR		Call subroutine	$PC \leftarrow ADDR$ $Stack \leftarrow (PC) + 1$	1	0	1	ADDR (13 bits)												
	RT			Return from subroutine	$PC \leftarrow Stack$	0	0	0	0	0	0		0	0	1	0	0	0			
	RTI			Return from interrupt	$PC \leftarrow Stack$, $BANK \leftarrow Stack$, $CARRY \leftarrow Stack$	0	0	0	0	0	0		0	0	1	0	0	1			

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Instructions	Mnemonic	Operand		Function	Operations function	Instruction format															
		1st	2nd			f	e	d	c	b	a	9	8	7	6	5	4	3	2	1	0
Status register instructions	SS	SWR	N	Set status register	(Status W-reg) $N \leftarrow 1$	1	1	1	1	1	1	1	1	0	0	0	SWR			N	
	RS	SWR	N	Reset status register	(Status W-reg) $N \leftarrow 0$	1	1	1	1	1	1	1	1	0	0	1	SWR			N	
	TST	SRR	N	Test status register true	if (Status R-reg) $N = \text{all}$	1	1	1	1	1	1	1	1	0	1		SRR			N	
	TSF	SRR	N	Test status register false	if (Status R-reg) $N = \text{all}$	1	1	1	1	1	1	1	1	1	0		SRR			N	
	TUL	N		Test Unlock F/F	if Unlock F/F (N) = all 0s, then skip	0	0	0	0	0	0	0	0	0	1	1	0	1		N	
Hardware control instructions	PLL	M		Load M to PLL register	PLL reg \leftarrow PLL data	1	1	1	1	1	0		DH			DL			r		
	UCS	I		Set I to UCCW1	UCCW1 \leftarrow I	0	0	0	0	0	0	0	0	0	0	0	1		I		
	UCC	I		Set I to UCCW2	UCCW2 \leftarrow I	0	0	0	0	0	0	0	0	0	0	1	0		I		
	BEEP	I		Beep control	BEEP reg \leftarrow I	0	0	0	0	0	0	0	0	0	1	1	0		I		
	DZC	I		Dead zone control	DZC reg \leftarrow I	0	0	0	0	0	0	0	0	1	0	1	1		I		
	TMS	I		Set timer register	Timer reg \leftarrow I	0	0	0	0	0	0	0	0	1	1	0	0		I		
	IOS	PWn	N	Set port control word	IOS reg PWn \leftarrow N	1	1	1	1	1	1	1	0			PWn			N		
I/O instructions	IN	M	Pn	Input port data to M	$M \leftarrow (Pn)$	1	1	1	0	1	0		DH			DL			Pn		
	OUT	M	Pn	Output contents of M to port	$P1n \leftarrow M$	1	1	1	0	1	1		DH			DL			Pn		
	INR	M	Pn	Input port data to M	$M \leftarrow (Pn)$	0	0	1	1	1	0		DH			DL			Pn		
	SPB	P1n	N	Set port1 bits	$(Pn)N \leftarrow 1$	0	0	0	0	0	0	1	0			Pn			N		
	RPB	P1n	N	Reset port1 bits	$(Pn)N \leftarrow 0$	0	0	0	0	0	0	1	1			Pn			N		
	TPT	P1n	N	Test port1 bits, then skip if all bits specified are true	if $(Pn)N = \text{all 1s}$, then skip	1	1	1	1	1	1	0	0			Pn			N		
	TPF	P1n	N	Test port1 bits, then skip if all bits specified are false	if $(Pn)N = \text{all 0s}$, then skip	1	1	1	1	1	1	0	1			Pn			N		
Bank switching instructions	BANK	I		Select Bank	$BANK \leftarrow I$	0	0	0	0	0	0	0	0	0	1	1	1		I		
LCD instructions	LCDA	M	I	Output segment pattern to LCD digit direct	$LCD (DIGIT) \leftarrow M$	1	1	0	0	0	0		DH			DL			DIGIT		
	LCDB	M	I			1	1	0	0	0	1		DH			DL			DIGIT		
	LCPA	M	I	Output segment pattern to LCD digit through LA	$LCD (DIGIT) \leftarrow LA \leftarrow M$	1	1	0	0	1	0		DH			DL			DIGIT		
	LCPB	M	I			1	1	0	0	1	1		DH			DL			DIGIT		
Other instructions	HALT	I		Halt mode control	HALT reg \leftarrow I, then CPU clock stop	0	0	0	0	0	0	0	0	0	1	0	0		I		
	CKSTP			Clock stop	Stop x'tal OSC	0	0	0	0	0	0	0	0	0	1	0	1				
	NOP			No operation	No operation	0	0	0	0	0	0	0	0	0	0	0	0				

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